

ORDERING INFORMATION		
Temp. Range	Package	Part Number
- 40 °C to 85 °C	16-Pin PlasticDIP	DG308BDJ DG308BDJ-E3
		DG309BDJ DG309BDJ-E3
	16-Pin Narrow SOIC	DG308BDY DG308BDY-E3 DG308BDY-T1 DG308BDY-T1-E3
		DG309BDY DG309BDY-E3 DG309BDY-T1 DG309BDY-T1-E3
	16-Pin TSSOP	DG308BDQ DG308BDQ-E3 DG308BDQ-T1 DG308BDQ-T1-E3
		DG309BDQ DG309BDQ-E3 DG309BDQ-T1 DG309BDQ-T1-E3

ABSOLUTE MAXIMUM RATINGS			
Parameter		Limit	Unit
Voltages Referenced, V ₊ to V ₋		44	V
GND		25	
Digital Inputs ^a , V _S , V _D		(V ₋) - 2 to (V ₊) + 2 or 30 mA, whichever occurs first	
Current, Any Terminal		30	mA
Peak Current, S or D (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature	(AK Suffix)	- 65 to 150	°C
	(DJ, DY and DQ Suffix)	- 65 to 125	
Power Dissipation (Package) ^b	16-Pin Plastic DIP ^c	470	mW
	16-Pin Narrow SOIC and TSSOP ^d	640	
	16-Pin CerDIP ^e	900	

Notes:

- Signals on S_X, D_X, or IN_X exceeding V₊ or V₋ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC board.
- Derate 6.5 mW/°C above 75 °C.
- Derate 7.6 mW/°C above 75 °C.
- Derate 12 mW/°C above 75 °C.

**SPECIFICATIONS^a**

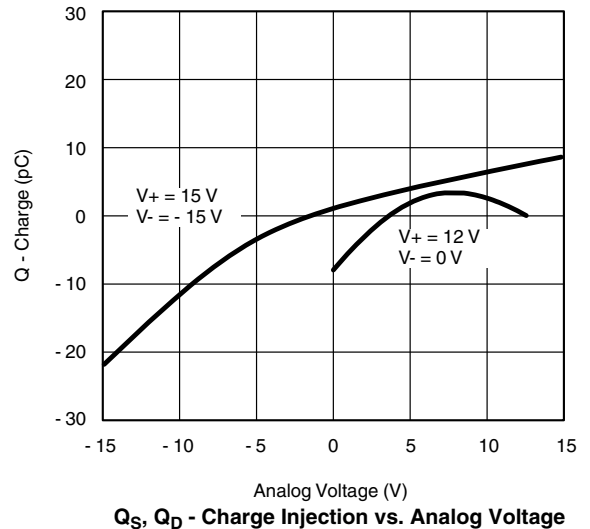
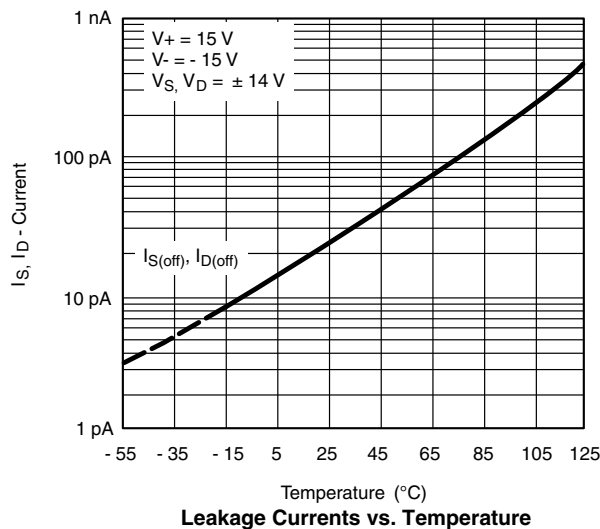
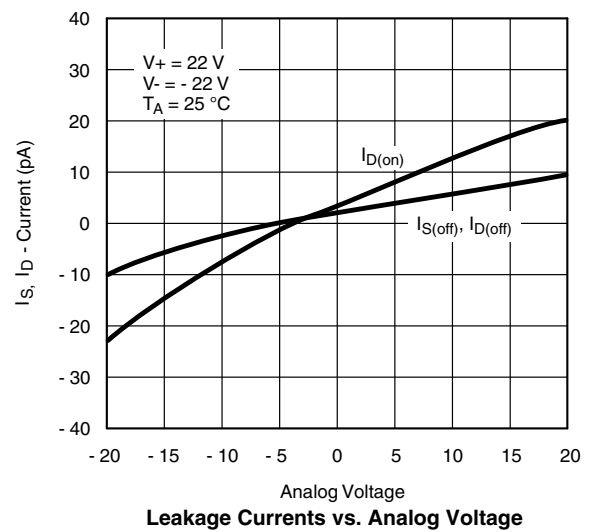
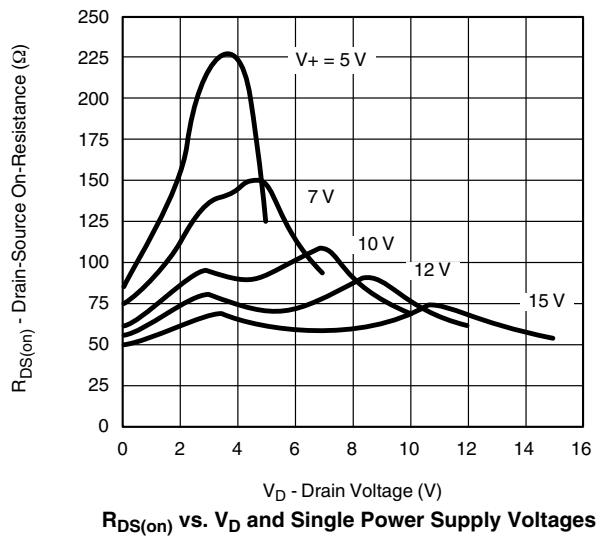
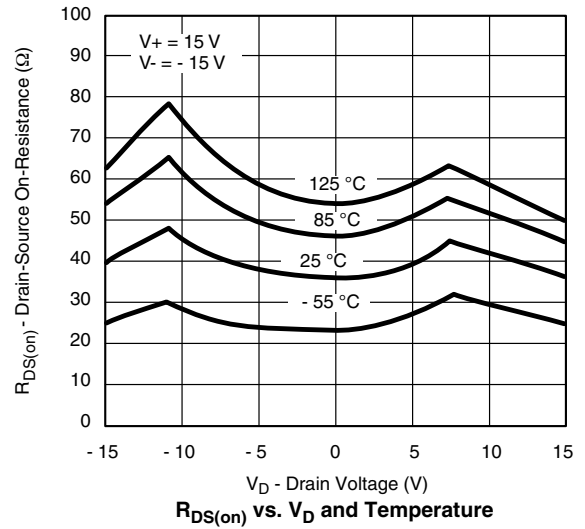
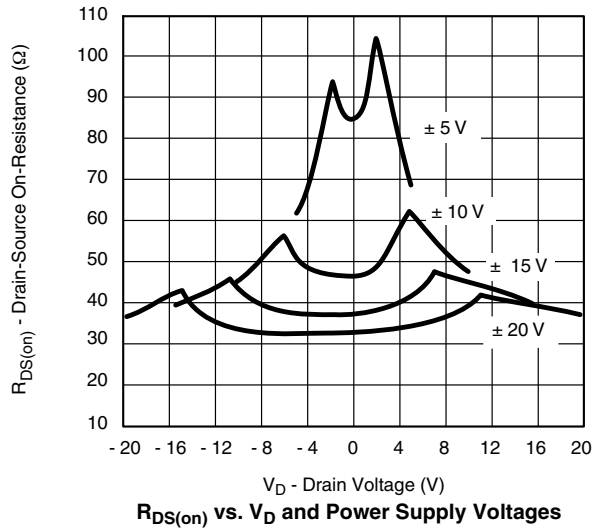
Parameter	Symbol	Test Conditions Unless Specified V ₊ = 15 V, V ₋ = - 15 V V _{IN} = 11 V, 3.5 V ^f	Temp. ^b	Typ. ^c	A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	R _{DS(on)}	V _D = ± 10 V, I _S = 1 mA	Room	45		85		85	Ω
R _{DS(on)} Match	ΔR _{DS(on)}		Full			100		100	
Source Off Leakage Current	I _{S(off)}	V _S = ± 14 V, V _D = ± 14 V	Room	± 0.01	- 0.5	0.5	- 0.5	0.5	nA
Drain Off Leakage Current	I _{D(off)}	V _D = ± 14 V, V _S = ± 14 V	Full	± 0.01	- 20	20	- 5	5	
Drain On Leakage Current	I _{D(on)}	V _S = V _D = ± 14 V	Room	± 0.02	- 40	40	- 10	10	
Digital Control									
Input, Voltage High	V _{INH}		Full		11		11		V
Input, Voltage Low	V _{INL}		Full			3.5		3.5	
Input Current	I _{INH} or I _{INL}	V _{INH} or V _{INL}	Full		- 1	1	- 1	1	μA
Input Capacitance	C _{IN}		Room	5					pF
Dynamic Characteristics									
Turn-On Time	t _{ON}	V _S = 3 V, see figure 2	Room			200		200	ns
Turn-Off Time	t _{OFF}		Room			150		150	
Charge Injection	Q	C _L = 1000 pF, V _g = 0 V, R _g = 0 Ω	Room	1					pC
Source-Off Capacitance	C _{S(off)}	V _S = 0 V, f = 1 MHz,	Room	5					pF
Drain-Off Capacitance	C _{D(off)}		Room	5					
Channel-On Capacitance	C _{D(on)}	V _D = V _S = 0 V, f = 1 MHz	Room	16					
Off-Isolation	OIRR	C _L = 15 pF, R _L = 50 Ω, V _S = 1 V _{RMS} , f = 100 kHz	Room	90					dB
Channel-to-Channel Crosstalk	X _{TALK}		Room	95					
Power Supply									
Positive Supply Current	I ₊	V _{IN} = 0 V or 15 V	Room			1		1	μA
Negative Supply Current	I ₋		Full		- 1	5	- 1	5	
Power Supply Range for Continuous Operation	V _{OP}		Full		± 4	± 22	± 4	± 22	V

SPECIFICATIONS ^a (for Single Supply)									
Parameter	Symbol	Test Conditions Unless Specified V ₊ = 12 V, V ₋ = 0 V V _{IN} = 11 V, 3.5 V ^f	Temp. ^b	Typ. ^c	A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		0	12	0	12	V
Drain-Source On-Resistance	R _{DS(on)}	V _D = 3 V, 8 V, I _S = 1 mA	Room Full	90		160 200		160 200	Ω
Dynamic Characteristics									
Turn-On Time	t _{ON}	V _S = 8 V, see figure 2	Room			300		300	ns
Turn-Off Time	t _{OFF}		Room			200		200	
Charge Injection	Q	C _L = 1 nF, V _{gen} = 6 V, R _{gen} = 0 Ω	Room	4					pC
Power Supply									
Positive Supply Current	I ₊	V _{IN} = 0 V or 12 V	Room Full			1 5		1 5	μA
Negative Supply Current	I ₋		Room Full		- 1 - 5		- 1 - 5		
Power Supply Range for Continuous Operation	V _{OP}		Full		4	44	4	44	V

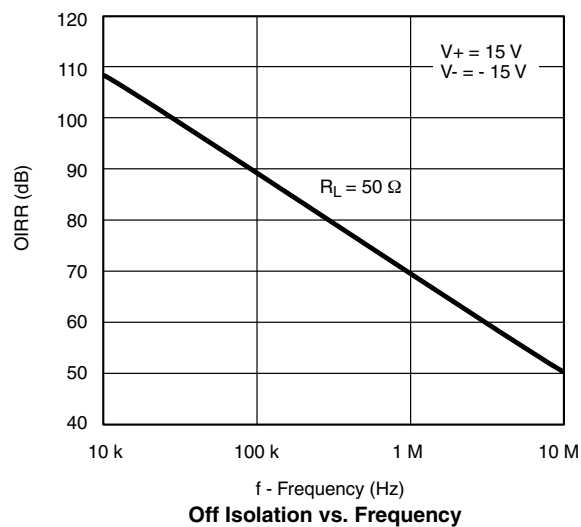
Notes:

- Refer to PROCESS OPTION FLOWCHART .
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



SCHEMATIC DIAGRAM (Typical Channel)

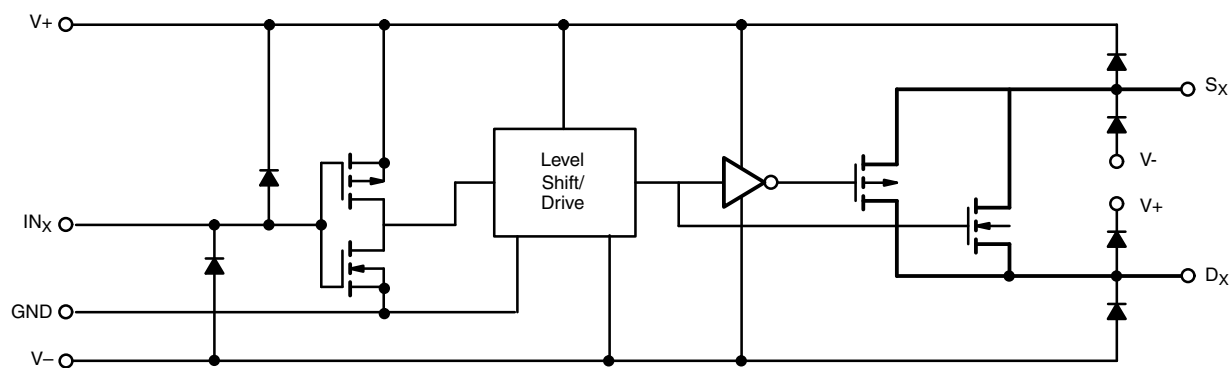
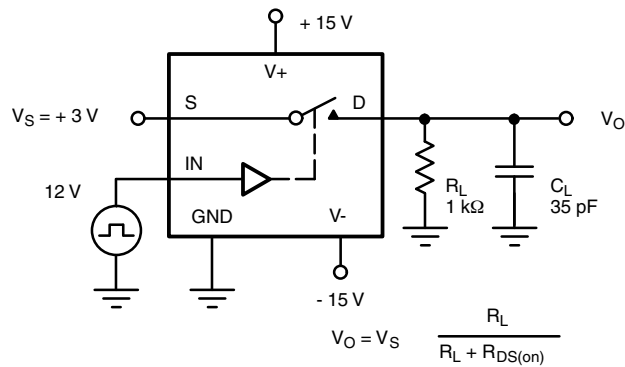
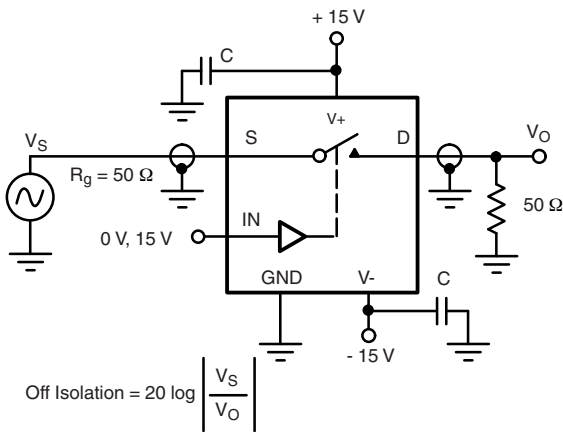
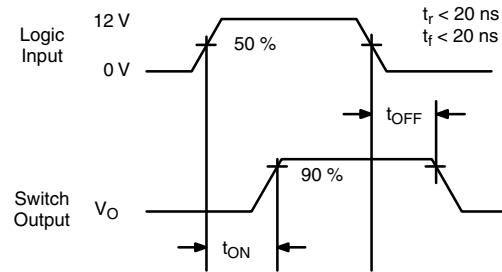
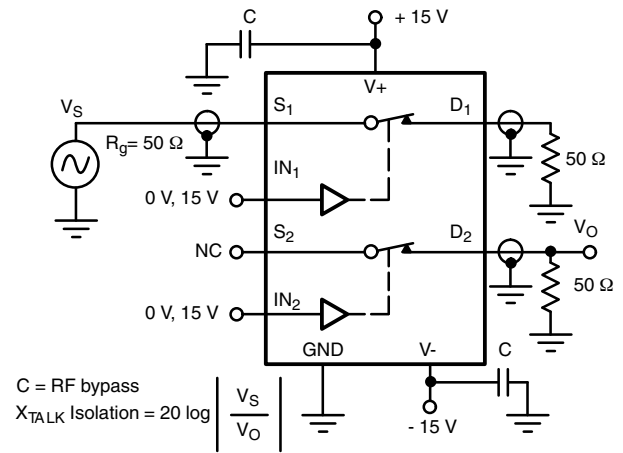
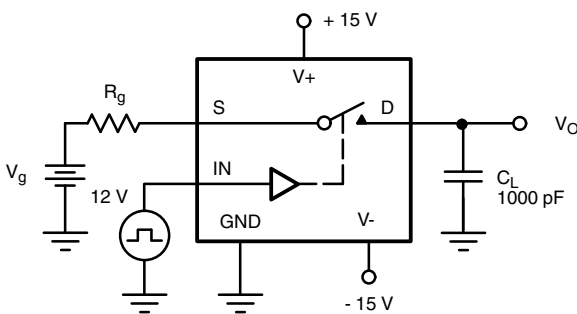
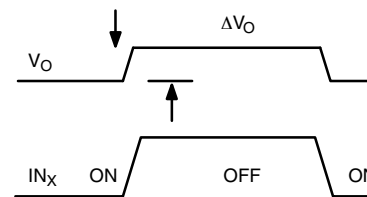


Figure 1.

TEST CIRCUITS

Figure 2. Switching Time

Figure 3. Off Isolation

Figure 4. Channel-to-Channel Crosstalk

Figure 5. Charge Injection


ΔV_O = measured voltage error due to charge injection
The charge injection in coulombs is $Q = C_L \times \Delta V_O$

APPLICATIONS

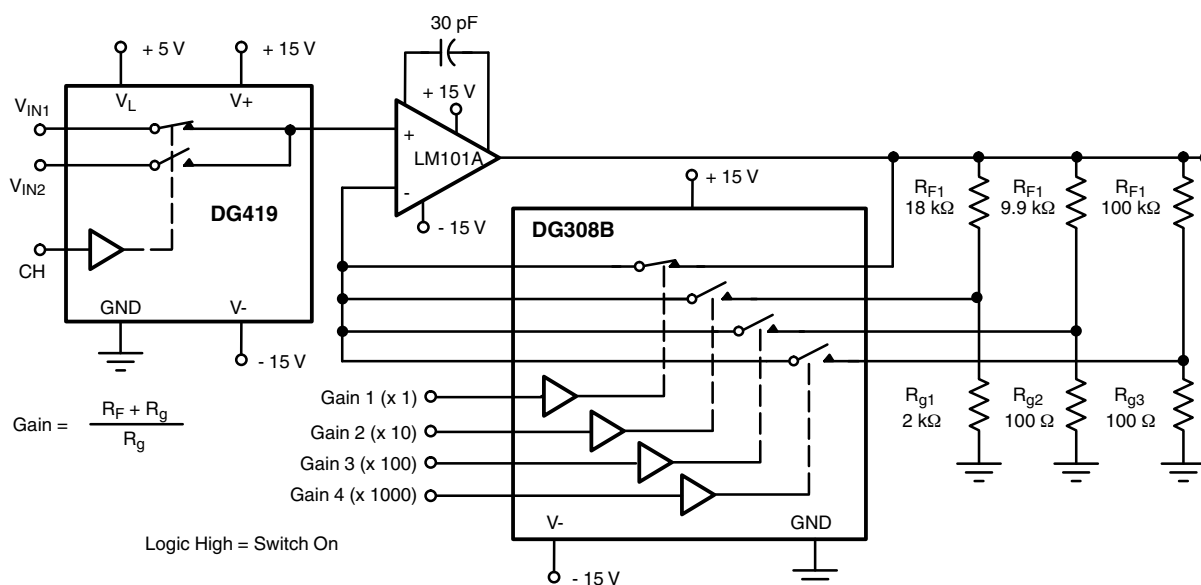


Figure 6. A Precision Amplifier with Digitally Programmable Inputs and Gains

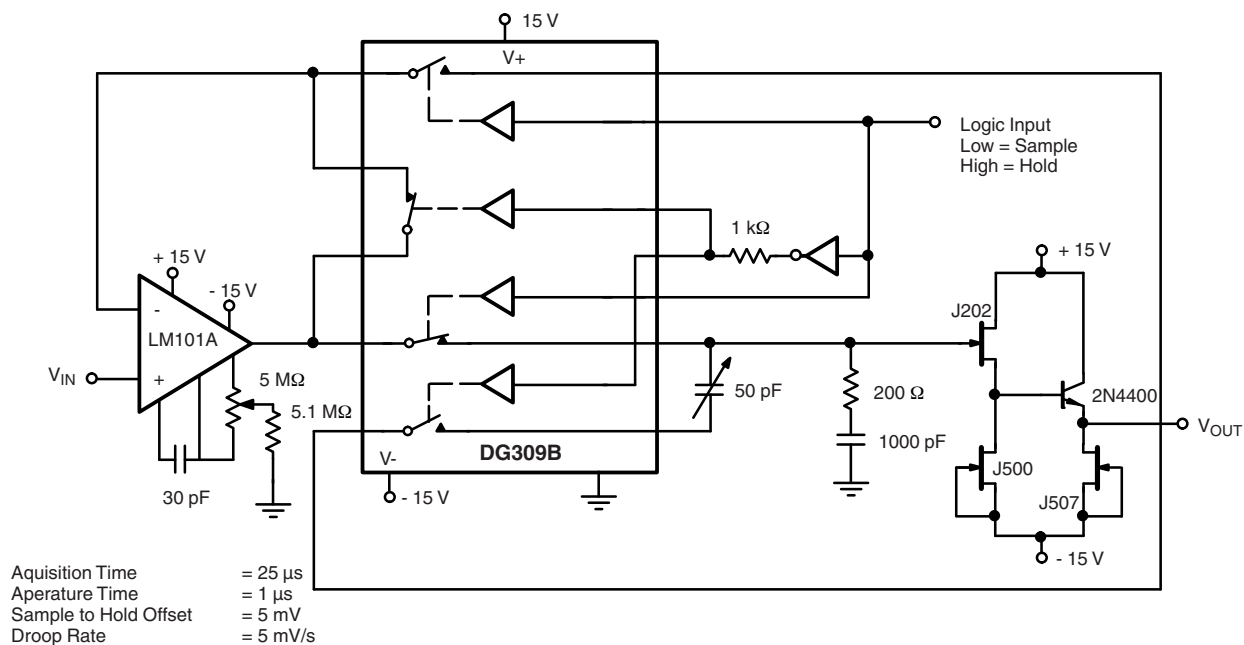
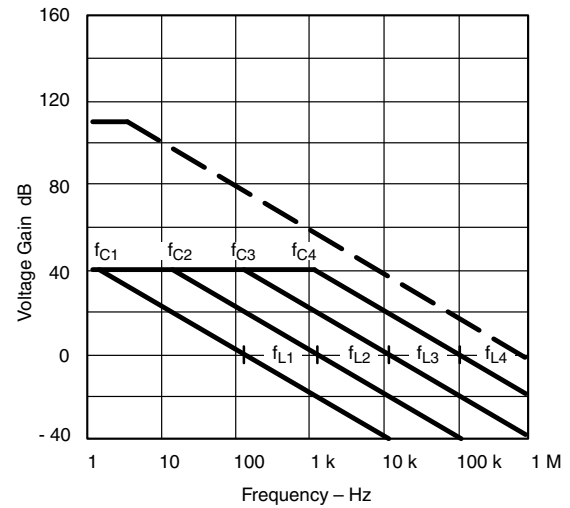
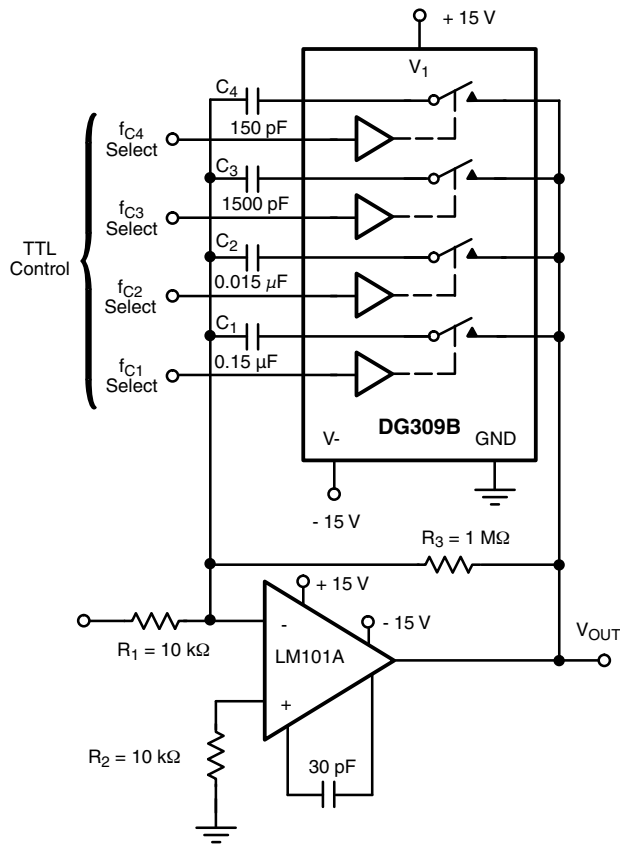


Figure 7. Sample-and-Hold

APPLICATIONS



$$A_L \text{ (Voltage Gain Below Break Frequency)} = \frac{R_3}{R_1} = 100 \text{ (40 dB)}$$

$$f_C \text{ (Break Frequency)} = \frac{1}{2\pi R_3 C_X}$$

$$f_L \text{ (Unity Gain Frequency)} = \frac{1}{2\pi R_1 C_X}$$

$$\text{Max Attenuation} = \frac{R_{DS(on)}}{10 \text{ k}\Omega} \approx -40 \text{ dB}$$

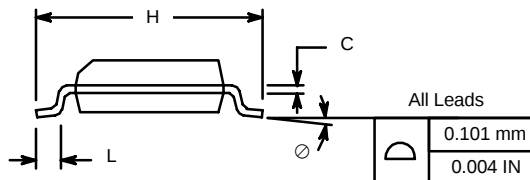
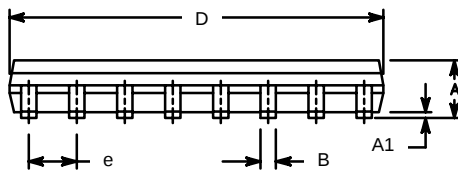
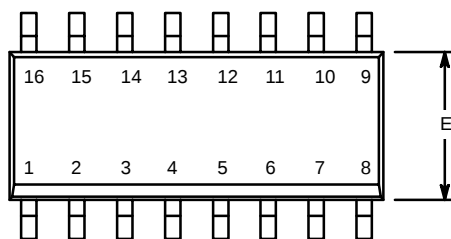
Figure 8. Active Low Pass Filter with Digitally Selected Break Frequency

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SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012

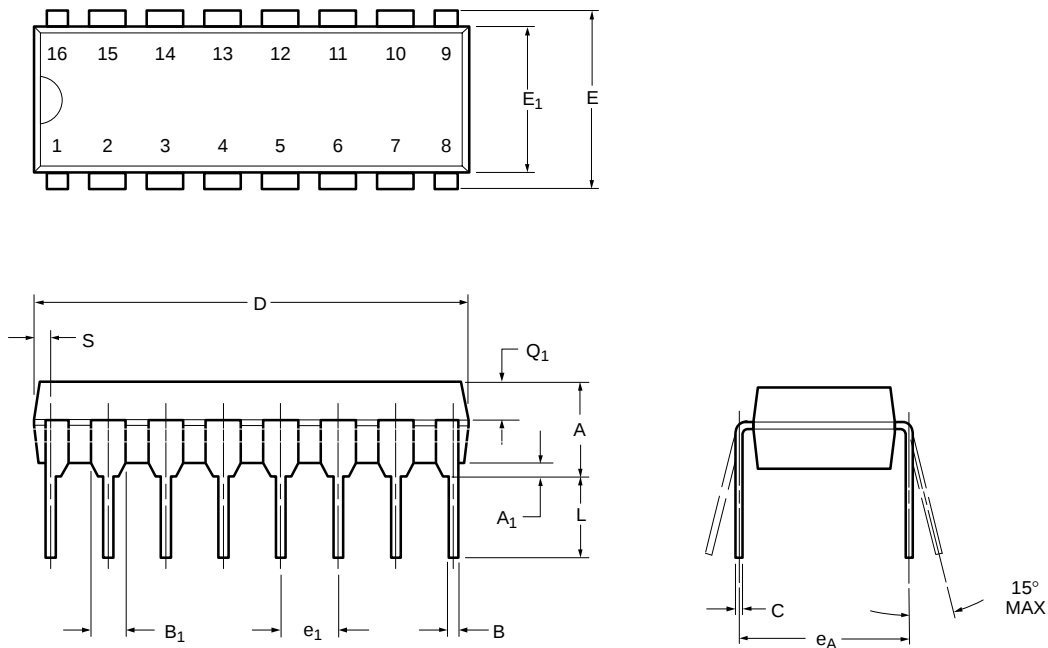


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



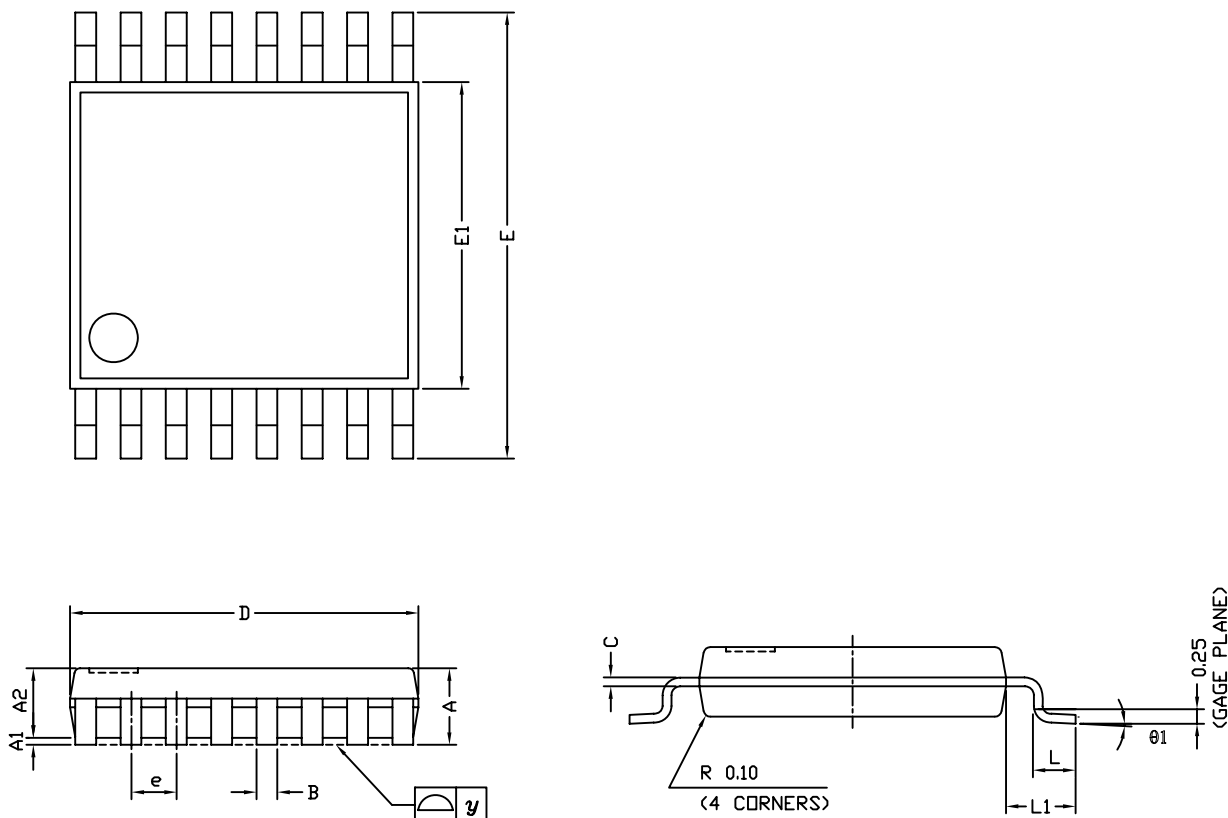
PDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A ₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B ₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E ₁	5.59	7.11	0.220	0.280
e ₁	2.29	2.79	0.090	0.110
e _A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q ₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060

ECN: S-03946—Rev. D, 09-Jul-01
DWG: 5482

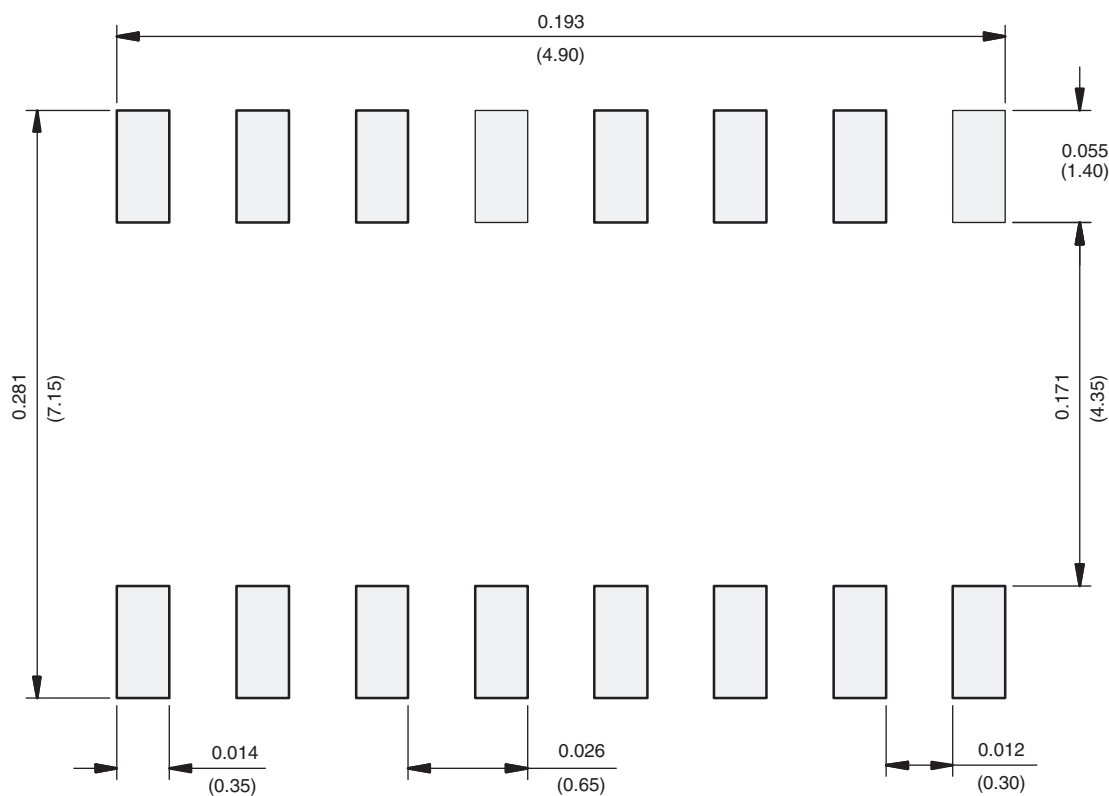
TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			

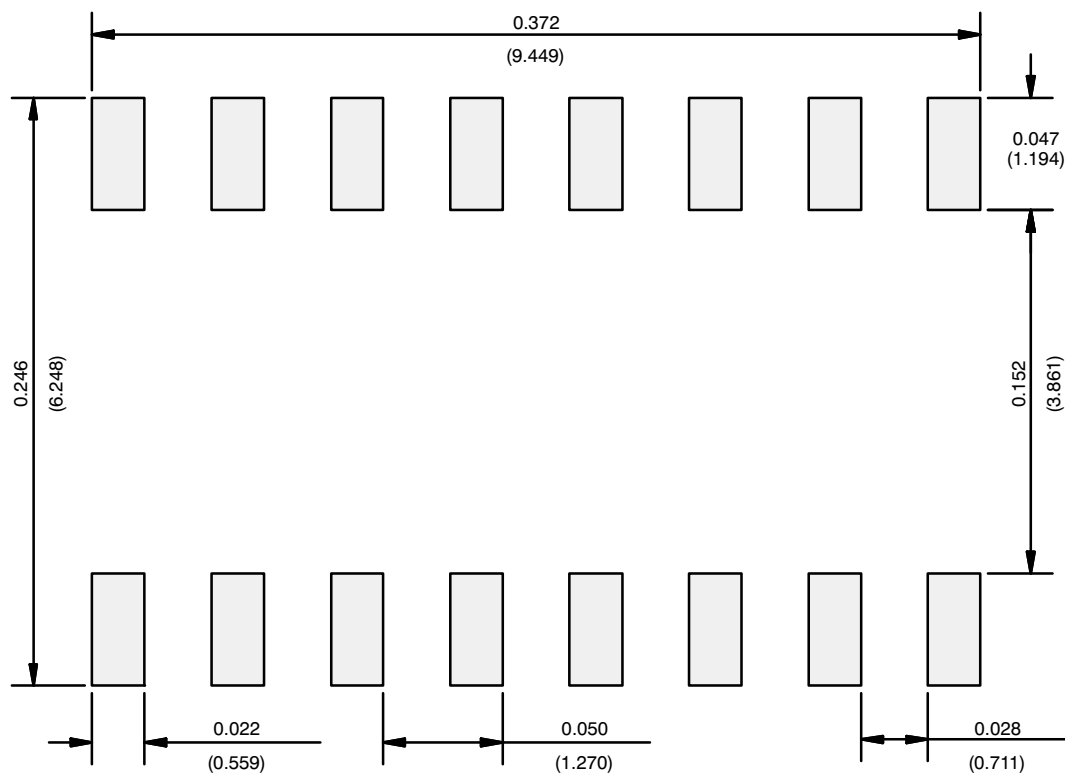


RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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